

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer



February 2010

FAN73932 Half-Bridge Gate Drive IC

Features

- Floating Channel for Bootstrap Operation to +600V
- Typically 2.5A/2.5A Sourcing/Sinking Current Driving Capability
- Extended Allowable Negative V_S Swing to -9.8V for Signal Propagation at V_{BS}=15V
- High-Side Output in Phase of IN Input Signal
- 3.3V and 5V Input Logic Compatible
- Matched Propagation Delay for Both Channels
- Built-in Shutdown Function
- Built-in UVLO Functions for Both Channels
- Built-in Common-Mode dv/dt Noise Canceling Circuit
- Internal 400ns Minimum Dead-Time

Applications

- High-Speed Power MOSFET and IGBT Gate Driver
- Induction Heating
- High-Power DC-DC Converter
- Synchronous Step-Down Converter
- Motor Drive Inverter

Description

The FAN73932 is a half-bridge, gate-drive IC with shutdown and dead-time functions which can drive high-speed MOSFETs and IGBTs that operate up to +600V. It has a buffered output stage with all NMOS transistors designed for high pulse current driving capability and minimum cross-conduction.

Fairchild's high-voltage process and common-mode noise canceling techniques provide stable operation of the high-side driver under high dv/dt noise circumstances. An advanced level-shift circuit offers high-side gate driver operation up to V_S =-9.8V (typical) for V_{RS} =15V.

The UVLO circuit prevents malfunction when V_{DD} and V_{BS} are lower than the specified threshold voltage.

The high-current and low-output voltage drop feature makes this device suitable for all kinds of half- and full-bridge inverters, like motor drive inverter, switching mode power supply, induction heating, and high-power DC-DC converter applications.

8-SOP



Ordering Information

Part Number	Package	Operating Temperature Range	Eco Status	Packing Method
FAN73932M	8-SOP	-40°C to +125°C	RoHS	Tube
FAN73932MX	0-30F	-40 C t0 +125 C NONS		Tape & Reel



For Fairchild's definition of Eco Status, please visit: http://www.fairchildsemi.com/company/green/rohs_green.html.

Typical Application Diagrams

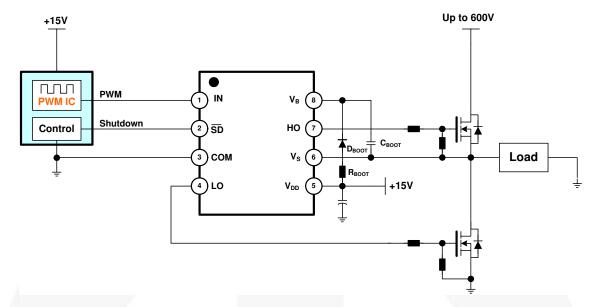


Figure 1. Typical Application Circuit

Internal Block Diagram

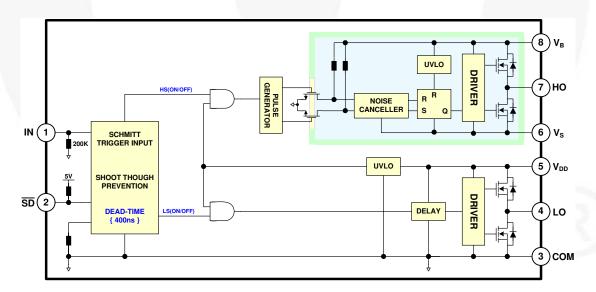


Figure 2. Functional Block Diagram

Pin Configuration

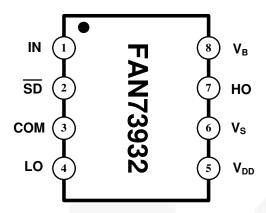


Figure 3. Pin Configuration (Top View)

Pin Definitions

Pin #	Name	Description
1	IN	Logic Input for High-Side and Low-Side Gate Driver Output, In-Phase with HO
2	SD	Logic Input for Shutdown
3	COM	Ground
4	LO	Low-Side Driver Return
5	V _{DD}	Supply Voltage
6	V _S	High-Voltage Floating Supply Return
7	НО	High-Side Driver Output
8	V _B	High-Side Floating Supply

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Min.	Max.	Unit
V _B	High-Side Floating Supply Voltage	-0.3	625.0	V
V _S	High-Side Floating Offset Voltage	V _B -25.0	V _B +0.3	V
V _{HO}	High-Side Floating Output Voltage	V _S -0.3	V _B +0.3	V
V _{LO}	Low-Side Output Voltage	-0.3	V _{DD} +0.3	V
V _{DD}	Low-Side and Logic Fixed Supply Voltage	-0.3	25.0	V
V _{IN}	Logic Input Voltage (IN)	-0.3	V _{DD} +0.3	V
V _{SD}	Logic Input Voltage (SD)	-0.3	5.5	V
COM	Logic Ground and Low-Side Driver Return	V _{DD} -25.0	V _{DD} +0.3	V
dV _S /dt	Allowable Offset Voltage Slew Rate		± 50	V/ns
P_{D}	Power Dissipation ^(1, 2, 3)		0.625	W
$\theta_{\sf JA}$	Thermal Resistance		200	°C/W
T _J	Junction Temperature		+150	°C
T _{STG}	Storage Temperature	-55	+150	°C

Notes:

- 1. Mounted on 76.2 x 114.3 x 1.6mm PCB (FR-4 glass epoxy material).
- 2. Refer to the following standards:
 - JESD51-2: Integral circuits thermal test method environmental conditions natural convection;
 - JESD51-3: Low effective thermal conductivity test board for leaded surface mount packages
- 3. Do not exceed P_D under any circumstances.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Unit
V _B	High-Side Floating Supply Voltage	V _S +10	V _S +20	V
V _S	High-Side Floating Supply Offset Voltage	6-V _{DD}	600	V
V _{HO}	High-Side Output Voltage	V _S	V_{B}	V
V _{DD}	Low-Side and Logic Fixed Supply Voltage	10	20	V
V_{LO}	Low-Side Output Voltage	COM	V_{DD}	V
V _{IN}	Logic Input Voltage (IN)	COM	V_{DD}	V
V _{SD}	Logic Input Voltage (SD)(4)	COM	5	V
T _A	Operating Ambient Temperature	-40	+125	°C

Note:

4. Shutdown (SD) input is internally clamped with 5.2V.

Electrical Characteristics

 $V_{BIAS}(V_{DD},\ V_{BS})$ =15.0V, COM=0V, and T_A = 25°C, unless otherwise specified. The V_{IN} and I_{IN} parameters are referenced to COM and are applicable to the respective input leads: IN and \overline{SD} . The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
POWER 9	SUPPLY SECTION		I	I		I
I _{QDD}	Quiescent V _{DD} Supply Current	V _{IN} =0V, SD =5V		320	700	μА
I _{QBS}	Quiescent V _{BS} Supply Current	V _{IN} =0V or 5V, SD=5V		50	120	μΑ
I _{PDD}	Operating V _{DD} Supply Current	f _{IN} =20KHz, No Load, SD=5V		700	1300	μА
I _{PBS}	Operating V _{BS} Supply Current	C _L =1nF, f _{IN} =20KHz, rms, SD=5V		420	800	μА
I _{SD}	Shutdown mode Supply Current	SD=0V, SD=5V		400	800	μΑ
I _{LK}	Offset Supply Leakage Current	V _B =V _S =600V			10	μΑ
BOOTST	RAPPED SUPPLY SECTION		I.			ı
V _{DDUV+} V _{BSUV+}	V _{DD} and V _{BS} Supply Under-Voltage Positive Going Threshold Voltage	V _{DD} =V _{BS} =Sweep	8	9	10	V
V _{DDUV-} V _{BSUV-}	V _{DD} and V _{BS} Supply Under-Voltage Negative Going Threshold Voltage	V _{DD} =V _{BS} =Sweep	7.4	8.4	9.4	٧
V _{DDUVH} - V _{BSUVH}	V _{DD} and V _{BS} Supply Under-Voltage Lockout Hysteresis Voltage	V _{DD} =V _{BS} =Sweep		0.6		V
INPUT LO	OGIC SECTION			1		
V _{IH}	Logic "1" Input Voltage for HO & Logic "0" for LO		2.5			V
V _{IL}	Logic "0" Input Voltage for HO & Logic "1" for LO				0.8	V
I_{IN+}	Logic Input High Bias Current	$V_{IN}=5V, \overline{SD}=0V$		25	60	μΑ
I _{IN-}	Logic Input Low Bias Current	V _{IN} =0V, SD =5V			3	μΑ
R _{IN}	Logic Input Pull-Down Resistance	7		200		ΚΩ
V _{SDCLAMP}	Shutdown (SD) Input Clamping Voltage			5.0	5.5	V
SD+	Shutdown (SD) input Positive-Going Threshold		2.5			V
SD-	Shutdown (SD) input Negative-Going Threshold	2			0.8	V
R_{PSD}	Shutdown (SD) Input Pull-Up Resistance			200		ΚΩ
GATE DR	RIVER OUTPUT SECTION					
V _{OH}	High-level Output Voltage (V _{BIAS} - V _O)	No Load			1.5	V
V _{OL}	Low-level Output Voltage	No Load			100	mV
I _{O+}	Output High, Short-Circuit Pulsed Current ⁽⁵⁾	V _{HO} =0V, V _{IN} =5V, PW ≤10μs	2.0	2.5		Α
I _{O-}	Output Low, Short-Circuit Pulsed Current ⁽⁵⁾	V _{HO} =15V,V _{IN} =0V, PW ≤10μs	2.0	2.5		Α
V _S	Allowable Negative V _S Pin Voltage for IN Signal Propagation to HO			-9.8	-7.0	٧

Note:

5 These parameters guaranteed by design.

Dynamic Electrical Characteristics

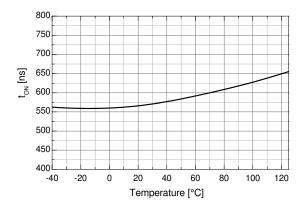
 $V_{BIAS}(V_{DD},\,V_{BS}) = 15.0V,\,COM = 0V,\,C_L = 1000pF,\,and\,T_A = 25^{\circ}C,\,unless\,otherwise\,specified.$

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
t _{ON}	Turn-On Propagation Delay Time ⁽⁶⁾	V _S =0V		600	850	ns
t _{OFF}	Turn-Off Propagation Delay Time	V _S =0V		200	350	ns
t _{SD}	Shutdown Propagation Delay Time			140	220	ns
Mt _{ON}	Delay Matching, HO and LO Turn-On			0	50	ns
Mt _{OFF}	Delay Matching, HO and LO Turn-Off			0	50	ns
t _R	Turn-On Rise Time	V _S =0V		25	50	ns
t _F	Turn-Off Fall Time	V _S =0V		20	35	ns
DT	Dead-Time: LO Turn-Off to HO Turn-On and HO Turn-Off to LO Turn-On		300	400	500	ns
MDT	Dead-time matching= DT _{LO-HO} - DT _{HO-LO}			0	50	ns

Note:

6. The turn-on propagation delay time included dead-time.

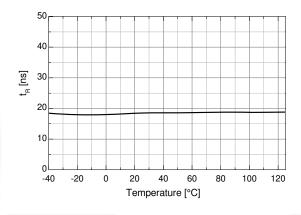
Typical Characteristics



280 240 200 $t_{\text{OFF}} \left[\text{ns} \right]$ 160 120 80 40l -40 -20 0 20 40 60 80 100 Temperature [°C]

Figure 4. Turn-On Propagation Delay vs. Temperature

Figure 5. Turn-Off Propagation Delay vs. Temperature



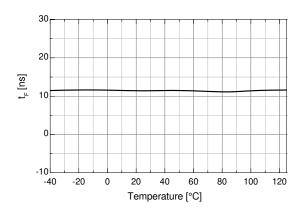
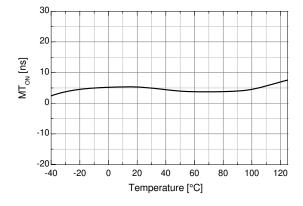


Figure 6. Turn-On Rise Time vs. Temperature





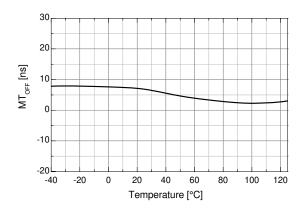
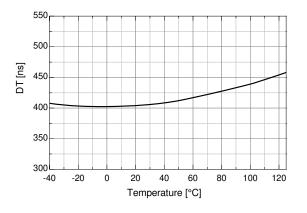


Figure 8. Turn-On Delay Matching vs. Temperature

Figure 9. Turn-Off Delay Matching vs. Temperature

Typical Characteristics (Continued)



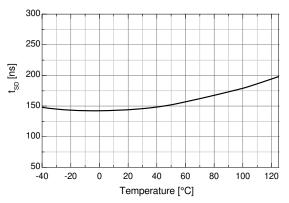
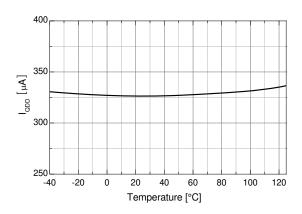


Figure 10. Dead-Time vs. Temperature

Figure 11. Shutdown Propagation Delay vs. Temperature



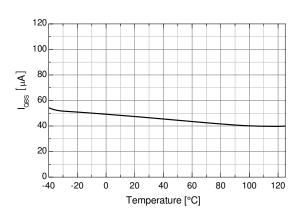
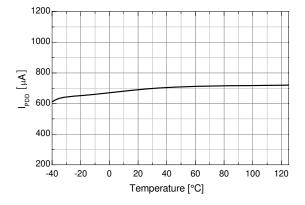


Figure 12. Quiescent V_{DD} Supply Current vs. Temperature

Figure 13. Quiescent V_{BS} Supply Current vs. Temperature



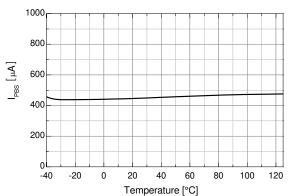
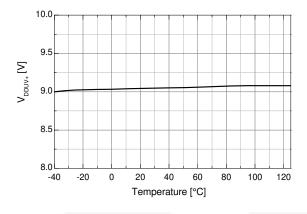


Figure 14. Operating V_{DD} Supply Current vs. Temperature

Figure 15. Operating V_{BS} Supply Current vs. Temperature

Typical Characteristics (Continued)



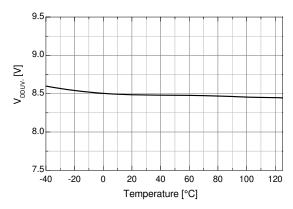
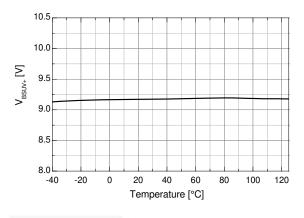


Figure 16. V_{DD} UVLO+ vs. Temperature

Figure 17. V_{DD} UVLO- vs. Temperature



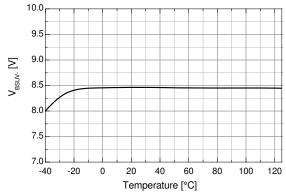
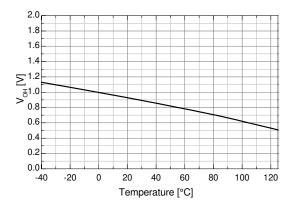
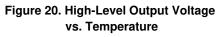


Figure 18. V_{BS} UVLO+ vs. Temperature

Figure 19. V_{BS} UVLO- vs. Temperature





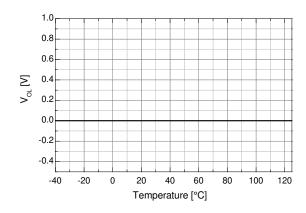
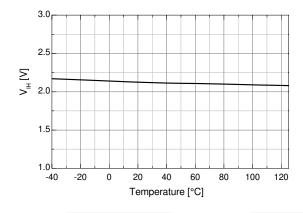


Figure 21. Low-Level Output Voltage vs. Temperature

Typical Characteristics (Continued)



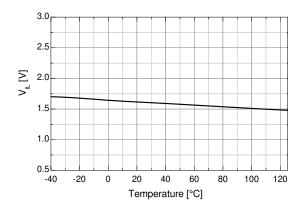
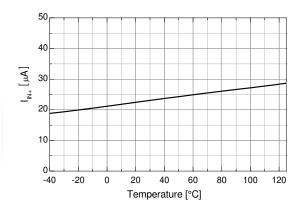


Figure 22. Logic High Input Voltage vs. Temperature

Figure 23. Logic Low Input Voltage vs. Temperature



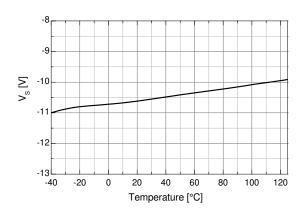


Figure 24. Logic Input High Bias Current vs. Temperature

Figure 25. Allowable Negative V_S Voltage vs. Temperature

Switching Time Definitions

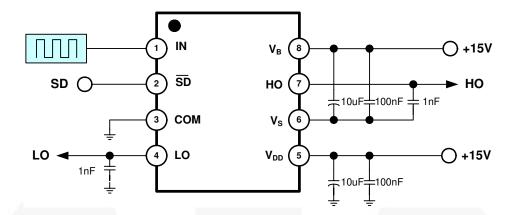


Figure 26. Switching Time Test Circuit

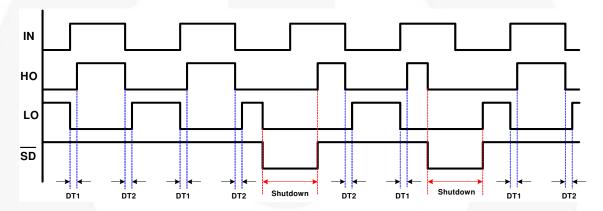


Figure 27. Input/Output Timing Diagram

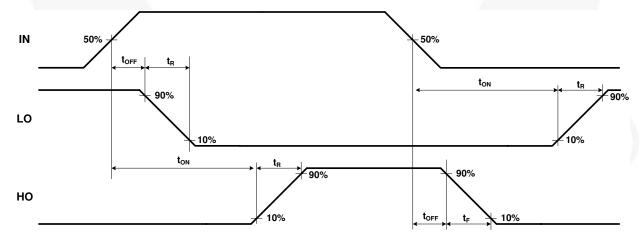


Figure 28. Switching Time Waveform Definition

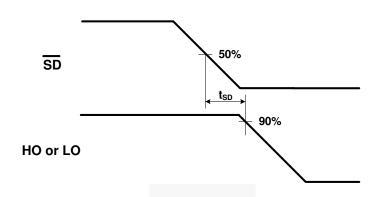


Figure 29. Shutdown Waveform Definition

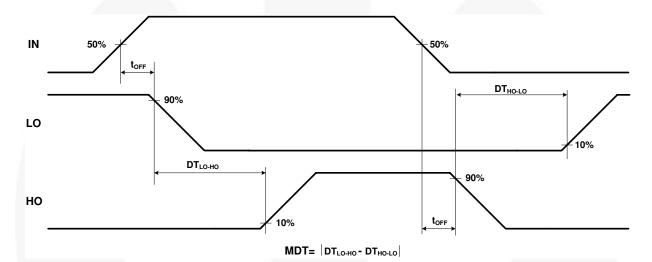


Figure 30. Dead-Time Waveform Definition

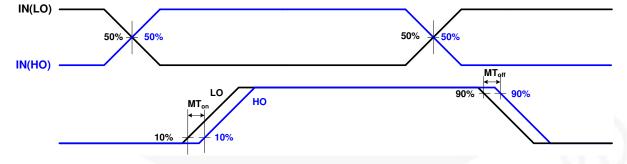


Figure 31. Delay Matching Waveform Definition

Mechanical Dimensions

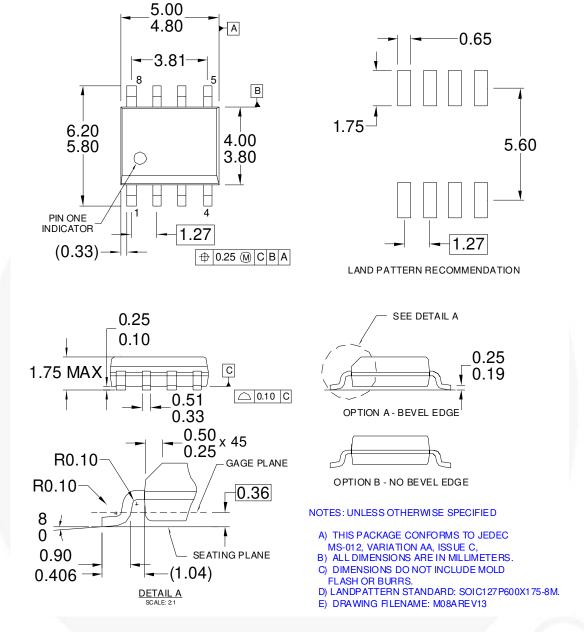


Figure 32. 8-Lead Small Outline Package (SOP)

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings: http://www.fairchildsemi.com/packaging/.





TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

Intended to be an exhaustive list of a AccuPower**
Auto-SPMT**
Build it Now**
CorePLUS**
CorePOWER**
CROSSVOLT**
CTL**
CTL**
Current Transfer Logic**
DEUXPEED**
Dual Cool**

EcoSPARK®
EfficientMax™

Fairchild®
Fairchild Semiconductor®
FACT Quiet Series™
FACT®
FAST°
FastvCore™
FETBench™

FETBench™ FlashWriter®* FPS™ F-PFS™ FRFET®
Global Power Resource
Green FPS™
Green FPS™ e-Series™

GmaxtM GTOTM IntelliMAXTM ISOPLANARTM MegaBuckTM MICROCOUPLERTM MicroFETTM

MicroPak™
MicroPak2™
MilerDrive™
MotionMax™
Motion-SPM™
OptoHiT™
OPTOLOGIC®
OPTOPLANAR®

PDP SPM™ Power-SPM™ PowerTrench® PowerXS™

Programmable Active Droop™

QFET[®] QS™ Quiet Series™ RapidConfigure™

Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™

SPM®
STEALTH™
SUPERSOT™3
SUPERSOT™3
SUPERSOT™4
SUPERSOT™4
SUPERSOT™4
SUPERSOT™5
SUPERSOT

The Power Franchise®

p wer tranchise TinyBoost™

TinyBusk**
TinyBusk**
TinyCalc**
TinyLogic*
TinyOPTO**
TinyPower**
TinyPvM**
TinyVvire**
TriFault Detect**
TRUECURRENT***
u.SerDes**

SerDes
UHC®
Ultra FRFET™
UniFET™
VCX™
VisualMax™
XS™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SECRIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification Product Status		Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Data sheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed Full Production Datasheet contains final specifications. Fairchild Semiconductor reserves the right to at any time without notice to improve the design.		Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

Rev. 147

^{*} Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hol

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81–3–5817–1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative